

熱のパラメータを用いた電源ICの熱設計

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ABSOLUTE MAXIMUM RATINGS ⁽¹⁾

Supply voltage (V_{IN}) -0.3V to +45V
VCP voltage (V_{CP}) V_{IN} to $V_{IN} + 6.5V$
 V_{OUTx} -0.3V to $V_{IN} + 0.3V$
PGND1, PGND2 to AGND -0.3V to +0.3V
All other pins to AGND -0.3V to +6.5V
Continuous power dissipation ($T_A = 25^\circ C$) ⁽²⁾
..... 2.6W

Junction temperature (T_J) 150°C
Lead temperature 260°C
Storage temperature -65°C to +150°C

1) Exceeding these ratings may damage the device.

Recommended Operating Conditions ⁽³⁾

Supply voltage (V_{IN}) 4V to 40V
Operating junction temp (T_J) -40°C to +125°C

3) The device is not guaranteed to function outside of its operating conditions.

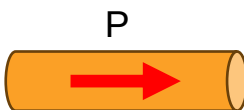
Thermal Metrics ⁽⁴⁾

θ_{JA} (junction-to-ambient) 44.3°C/W
 θ_{JC_TOP} (junction-to-case top) 37.5°C/W
 Ψ_{JT} (junction-to-top) 1.1°C/W

4) According to JEDEC JESD51-2/-5/-7/-8/-14.

熱の伝わり方

✓ 熱抵抗 θ

T_1  T_2 $\theta = \frac{T_1 - T_2}{P} [\text{°C/W}]$

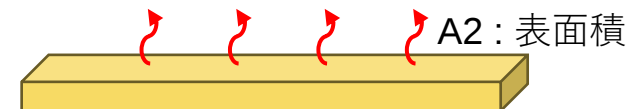
熱	熱流量 P [W]	温度差 dT [°C]	熱抵抗 θ [°C/W]
電気	電流 I [A]	電圧差 dV [V]	電気抵抗 R [Ω]

✓ 放熱経路

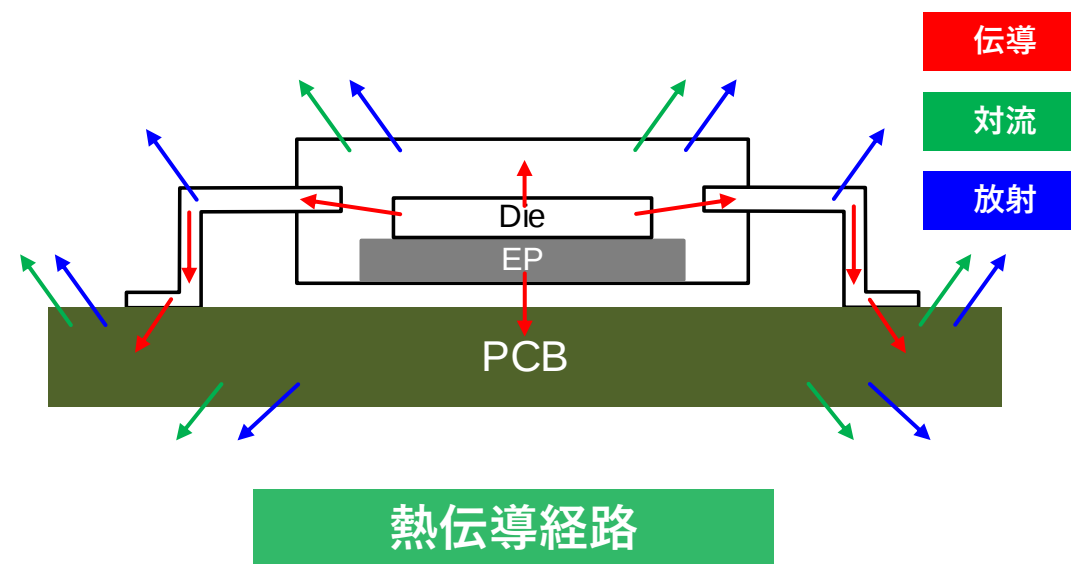
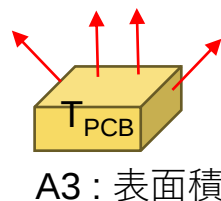
・伝導 $\theta_{CD} = \frac{L}{A_1 \times \lambda}$



・対流 $\theta_{CV} = \frac{1}{A_2 \times h}$

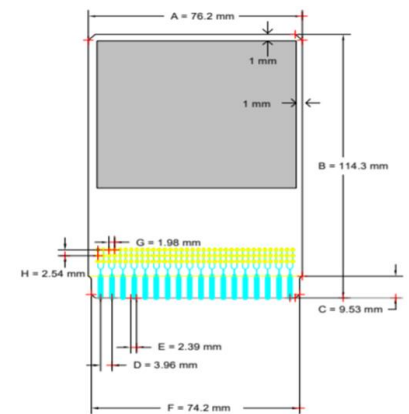
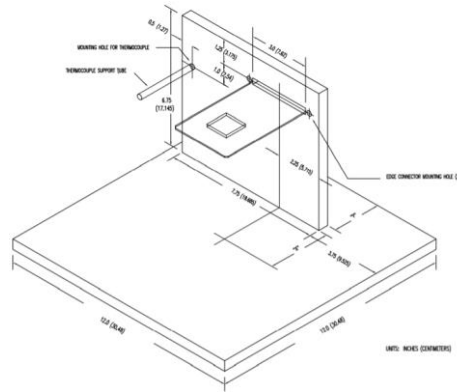
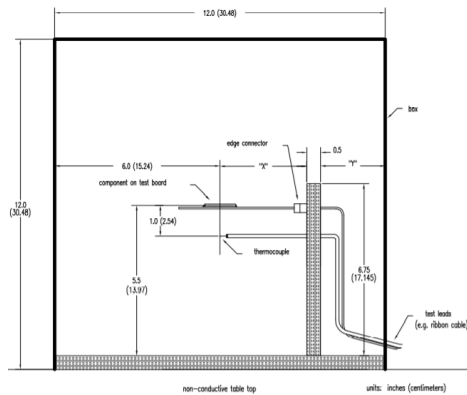


・放射 $\theta_{RD} = \frac{1}{A_3 \times \sigma \times \varepsilon \times (T_{PCB}^4 - T_{AMB}^4)}$



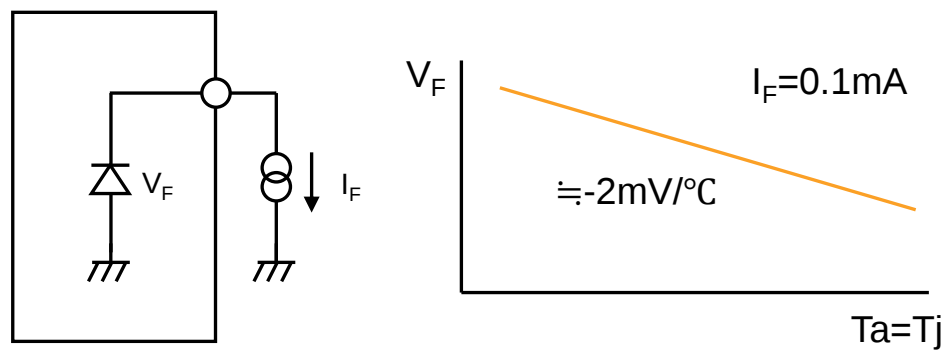
λ : 熱伝導率、 h : 対流熱伝導率、 σ : ボルツマン定数、 ε : 放射係数 (材料固有の値)

JEDEC JESD51 試験環境



測定環境

PCB



測定の事前準備

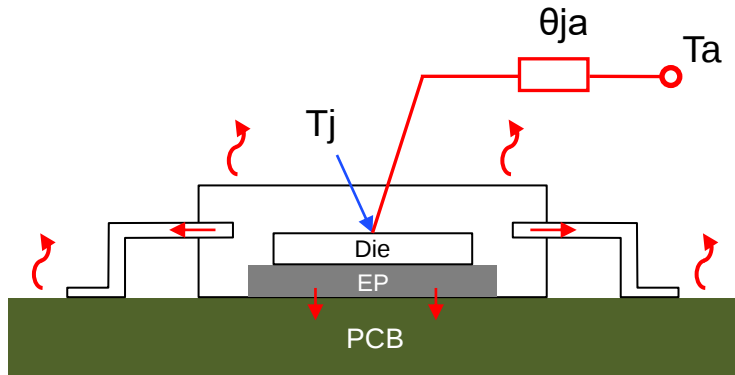
熱抵抗の測定

Thermal Metrics

θ_{JA} (junction-to-ambient).....44.3°C/W

θ_{JC_TOP} (junction-to-case top).....37.5°C/W

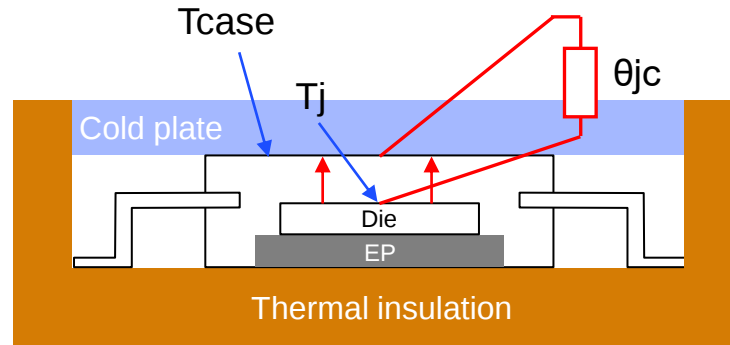
Ψ_{JT} (junction-to-top).....1.1°C/W



$$\theta_{ja} = \frac{T_j - T_a}{P} \text{ [}^\circ\text{C/W]}$$

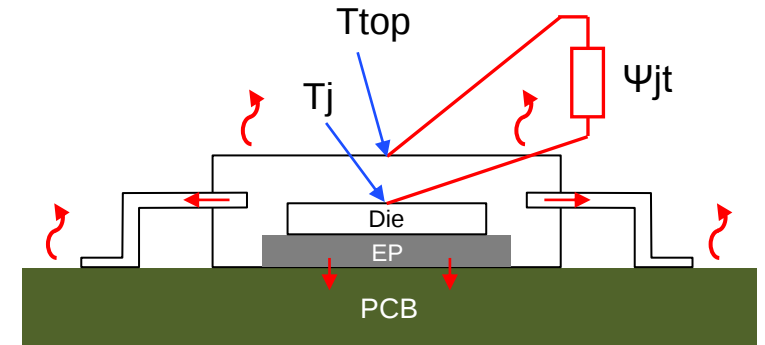
θ_{ja}

$$T_j = \theta_{ja} \times P + T_a \text{ [}^\circ\text{C]}$$



$$\theta_{jc} = \frac{T_j - T_{case}}{P} \text{ [}^\circ\text{C/W]}$$

θ_{jc}

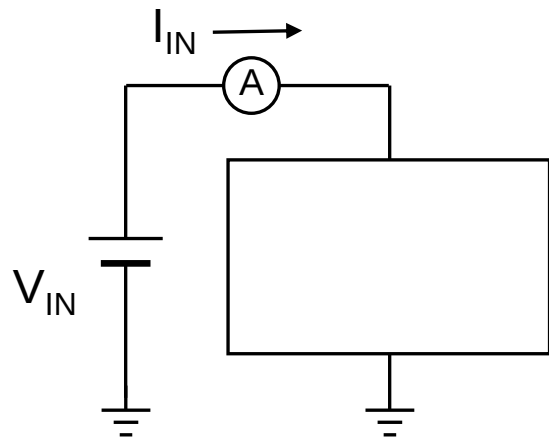


$$\psi_{jt} = \frac{T_j - T_{top}}{P} \text{ [}^\circ\text{C/W]}$$

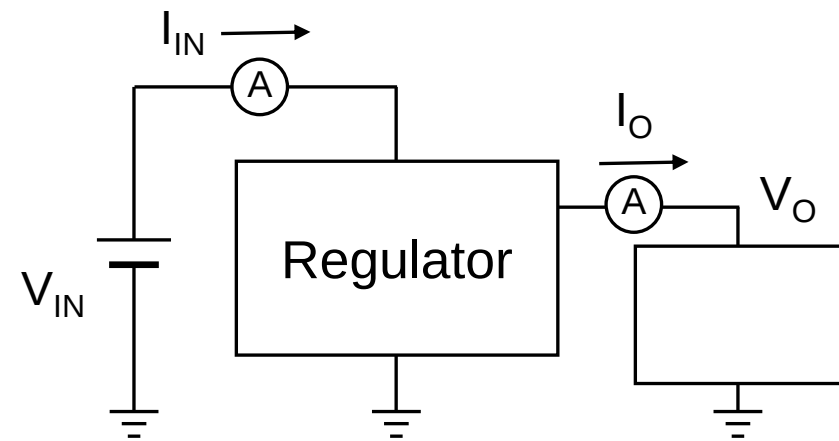
Ψ_{jt}

$$T_j = \psi_{jt} \times P + T_{top} \text{ [}^\circ\text{C]}$$

電源の消費電力

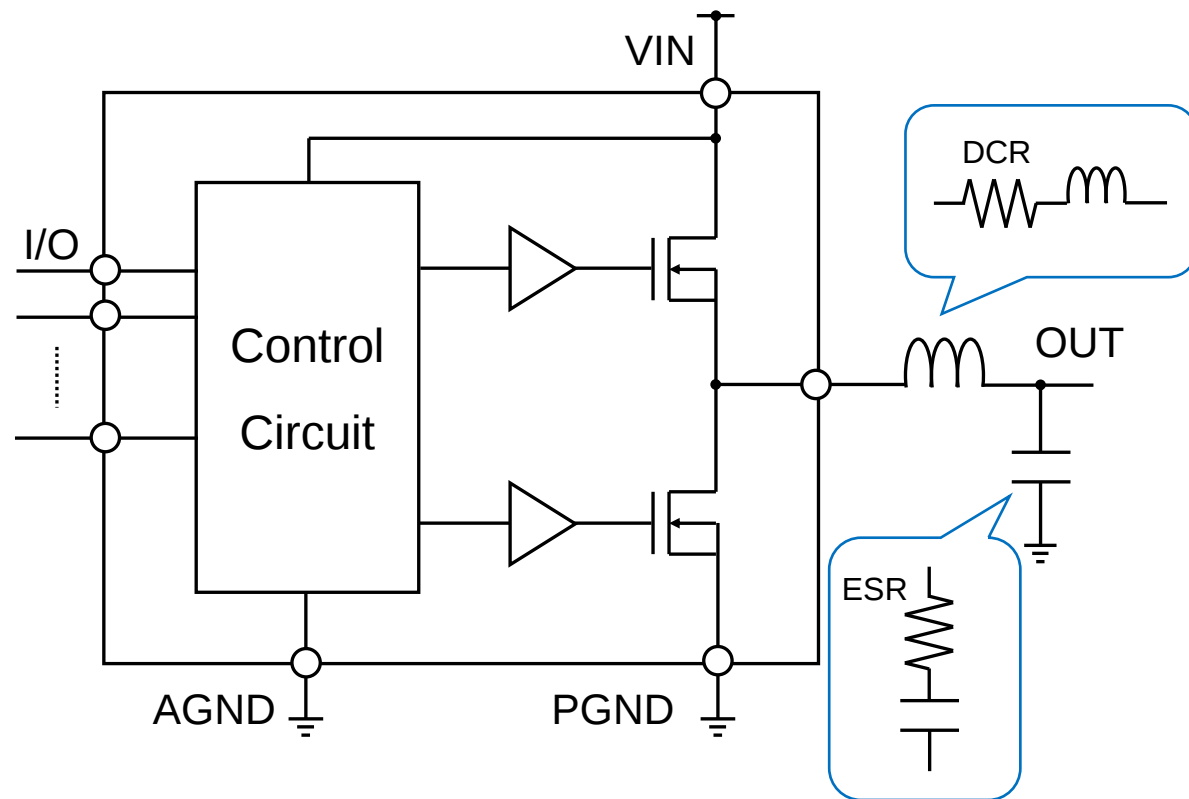


$$P = V_{IN} \times I_{IN}$$

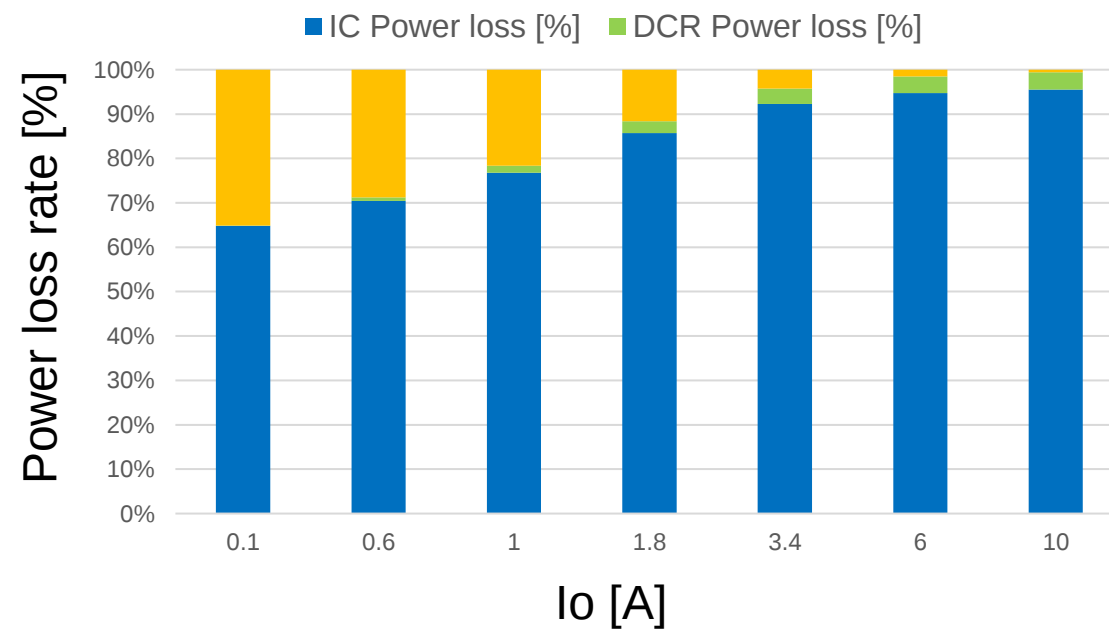


$$P = V_{IN} \times I_{IN} - V_O \times I_O$$

DCDCコンバータの消費電力



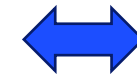
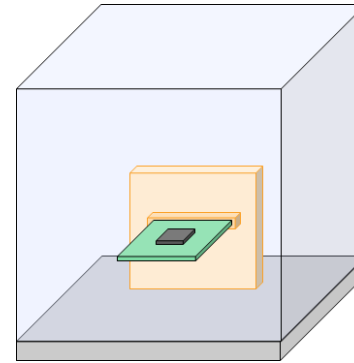
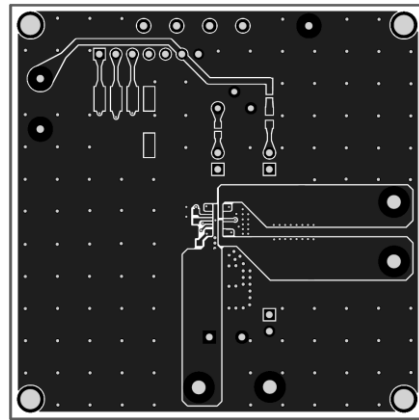
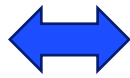
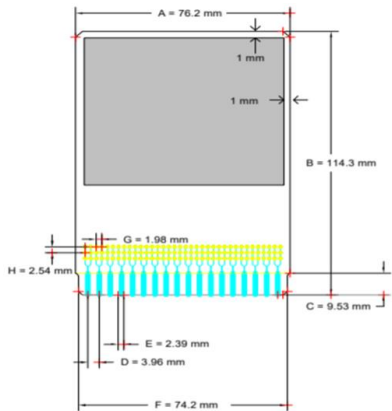
$$P_{loss} = P_{IC} + P_{DCR} + P_{ESR}$$



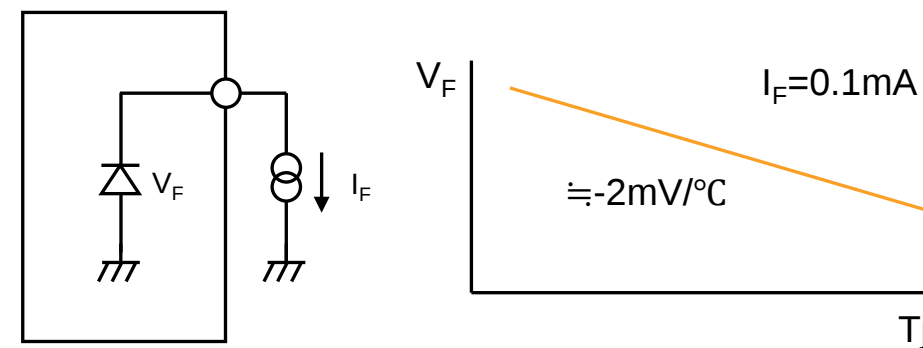
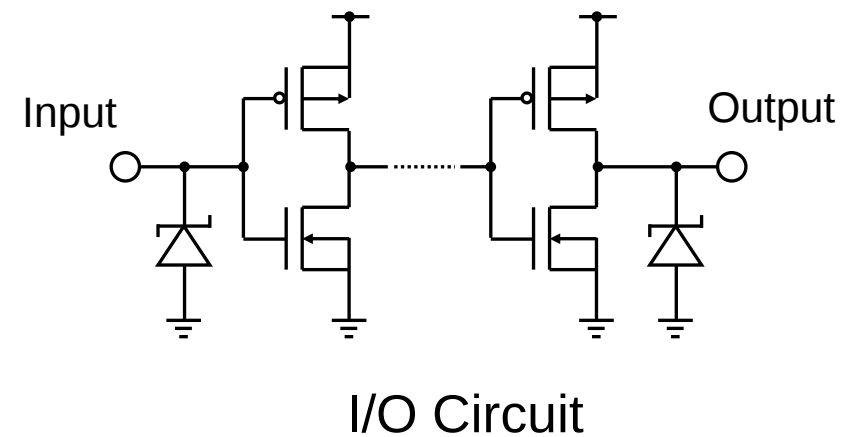
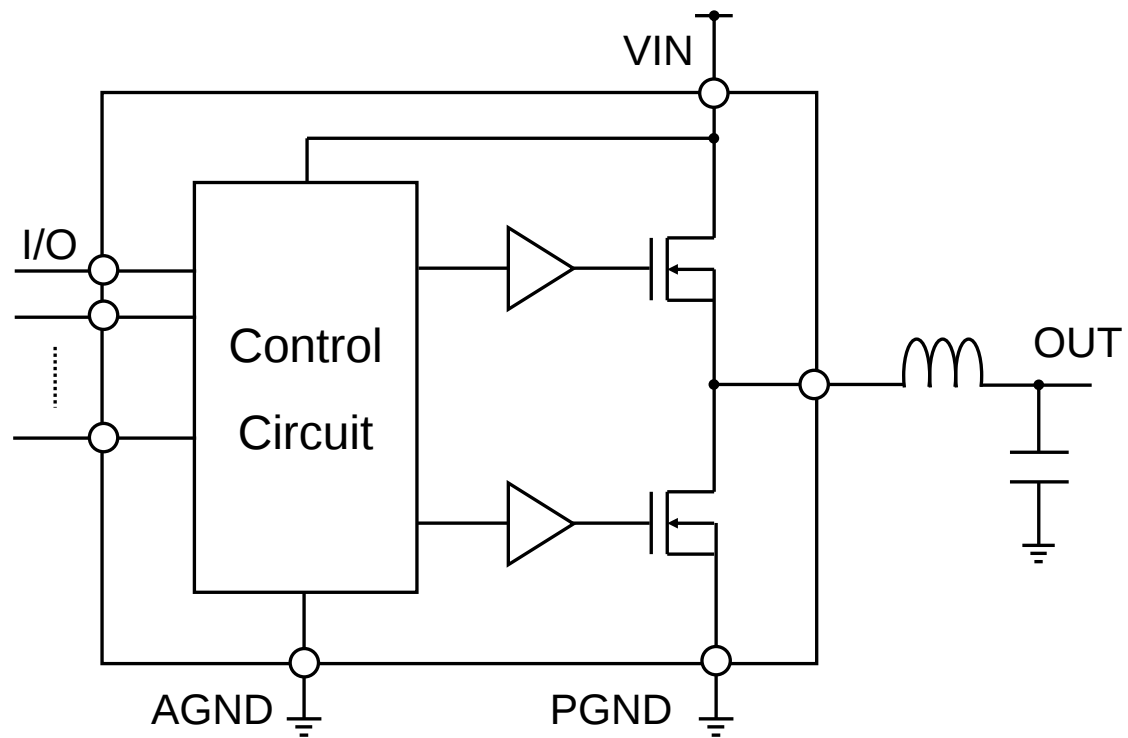
Tjの算出

$$Tj = \theta_{ja} \times P + Ta \text{ [}^{\circ}\text{C]}$$

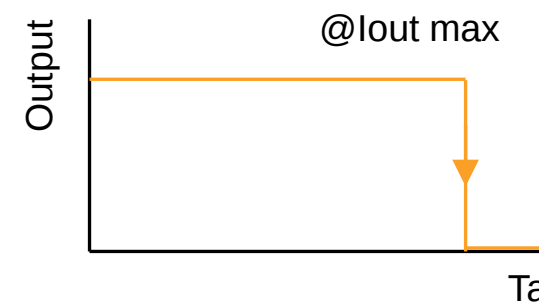
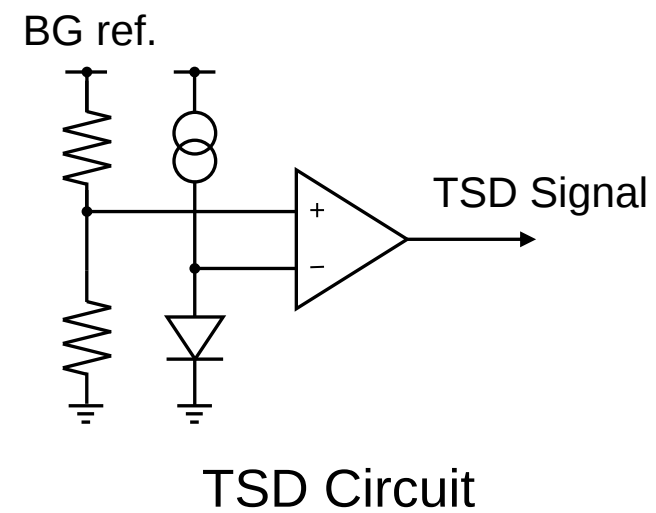
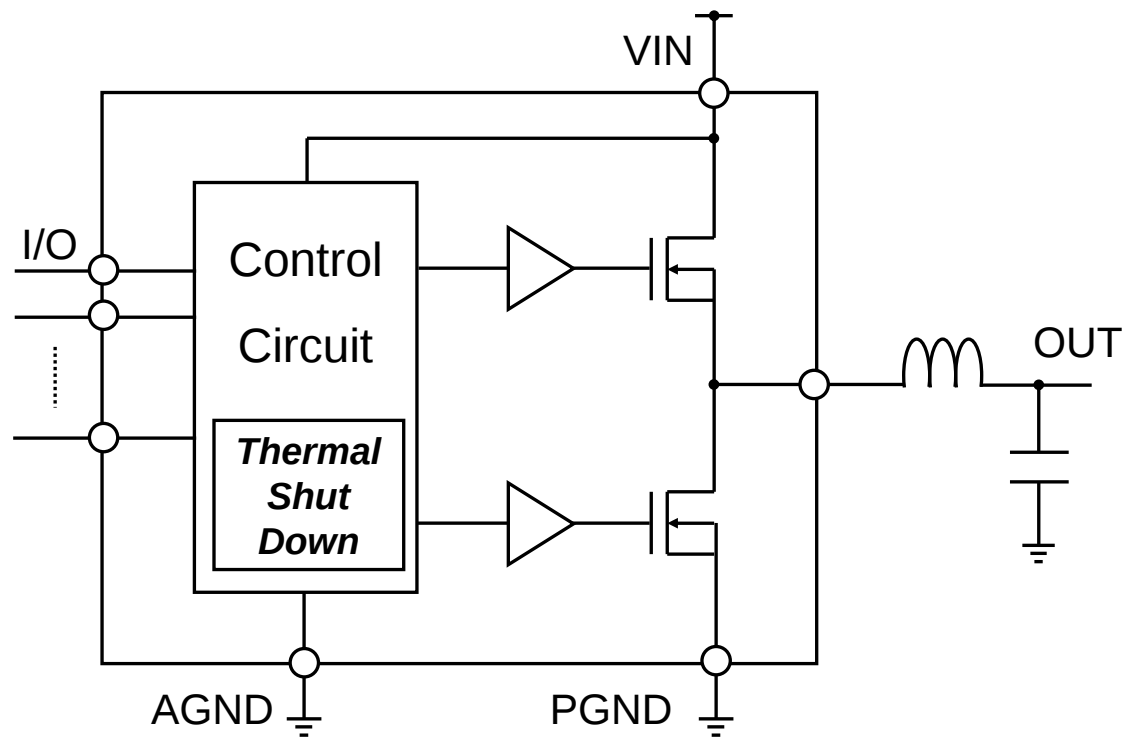
$$Tj = \psi_{jt} \times P + Ttop \text{ [}^{\circ}\text{C]}$$



Tjの実測



Tjの実測



Tjを低減するPCB設計

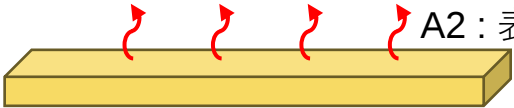
✓ 放熱経路

・伝導 $\theta_{CD} = \frac{L}{A_1 \times \lambda}$



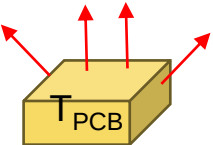
L: 長さ
A1: 断面積

・対流 $\theta_{CV} = \frac{1}{A_2 \times h}$



A2: 表面積

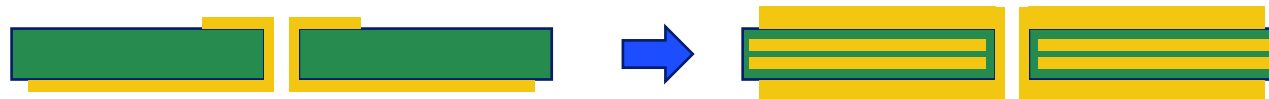
・放射 $\theta_{RD} = \frac{1}{A_3 \times \sigma \times \varepsilon \times (T_{PCB}^4 - T_{AMB}^4)}$



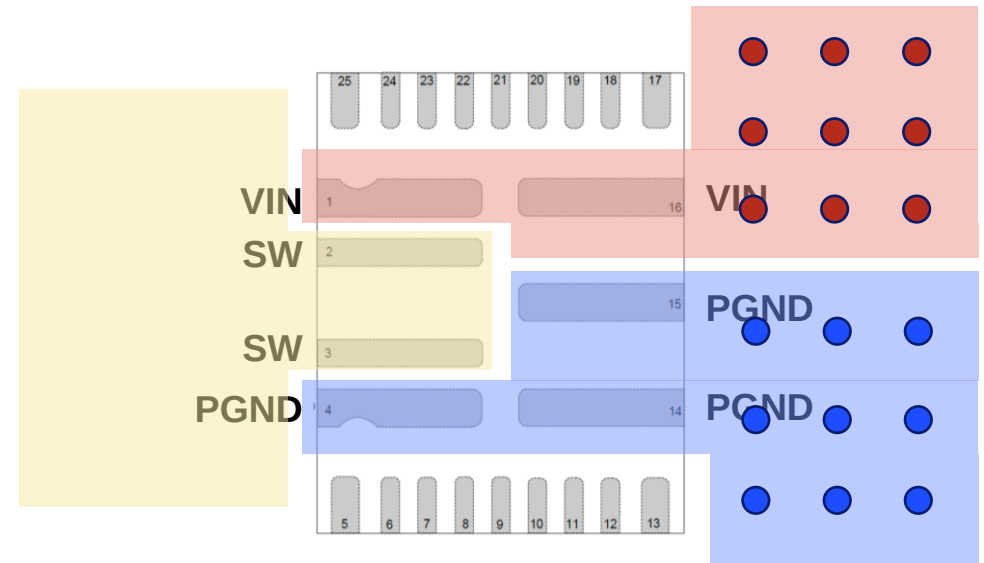
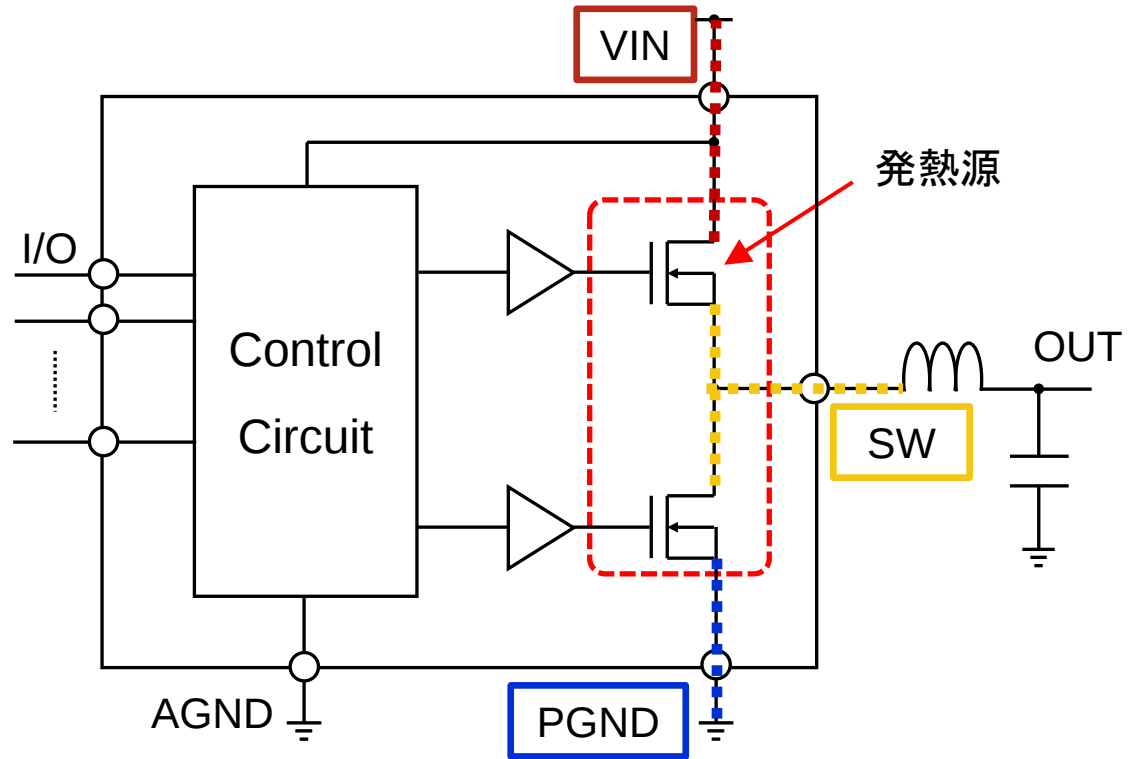
A3: 表面積

材料	熱伝導率 λ [W/mK]
銅	419
金	295
シリコン	162
半田	49
FR4	0.25

T=20°C, 1013.25hPa



PCBレイアウト例



サマリー

- ✓ 熱設計の重要性
- ✓ T_j を正しく把握
 - θ_{ja} 、 Ψ_{jt} を用いた算出
 - ダイオード/TSD機能を用いた測定
- ✓ 効果的なPCB設計
 - 伝熱を理解したPCBレイアウト